

EM513 THRU EM518

1.0 AMP SILICON RECTIFIERS



FEATURES

- * Low forward voltage drop
- * High current capability
- * High reliability
- * High surge current capability

MECHANICAL DATA

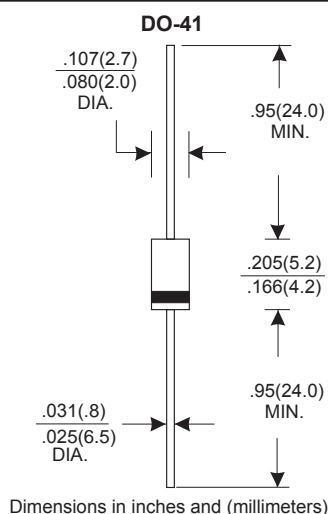
- * Case: Molded plastic
- * Epoxy: UL 94V-0 rate flame retardant
- * Lead: Axial leads, solderable per MIL-STD-202, method 208 guaranteed
- * Polarity: Color band denotes cathode end
- * Mounting position: Any
- * Weight: 0.28 grams
- * Lead Free Finish/RoHS Compliant

VOLTAGE RANGE

1600 to 2000 Volts

CURRENT

1.0 Ampere



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwise specified.
Single phase half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

TYPE NUMBER	EM513	EM516	EM518	UNITS
Maximum Recurrent Peak Reverse Voltage	1600	1800	2000	V
Maximum RMS Voltage	1120	1260	1400	V
Maximum DC Blocking Voltage	1600	1800	2000	V
Maximum Average Forward Rectified Current				
.375"(9.5mm) Lead Length at Ta=75°C		1.0		A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)		30		A
Maximum Instantaneous Forward Voltage at 1.0A		1.1		V
Maximum DC Reverse Current Ta=25°C		5.0		μA
at Rated DC Blocking Voltage Ta=100°C		50		μA
Typical Junction Capacitance (Note 1)		15		pF
Typical Thermal Resistance RθJA (Note 2)		50		°C/W
Operating and Storage Temperature Range Tj, Tstg		-65 — +150		°C

NOTES:

1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
2. Thermal Resistance from Junction to Ambient .375" (9.5mm) lead length.

RATING AND CHARACTERISTIC CURVES (EM513~EM518)

FIG.1-TYPICAL FORWARD CHARACTERISTICS

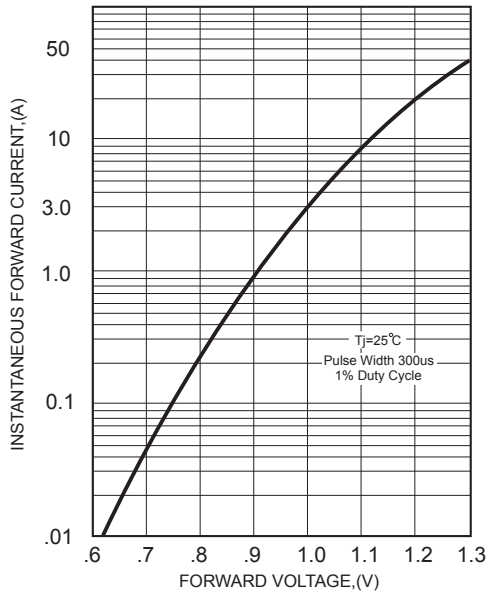


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

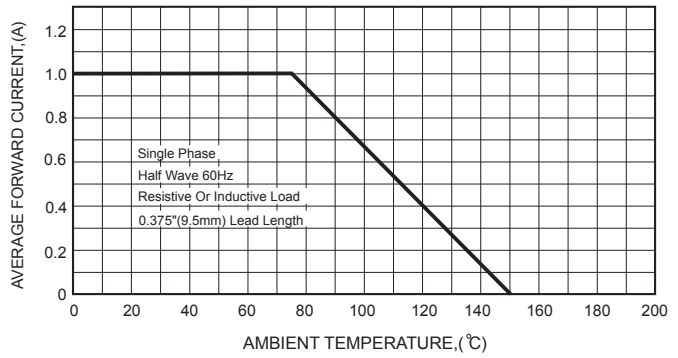


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

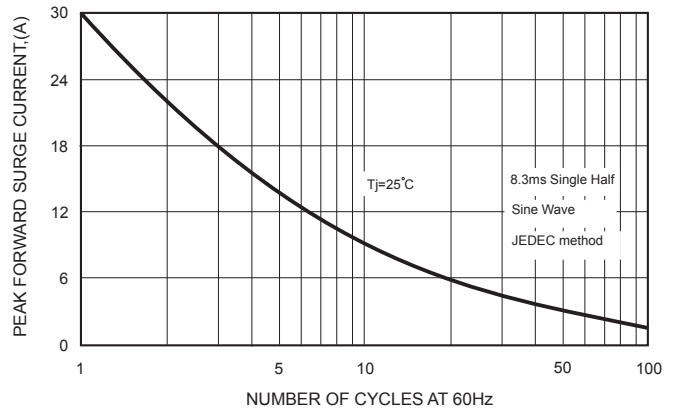


FIG.3 - TYPICAL REVERSE CHARACTERISTICS

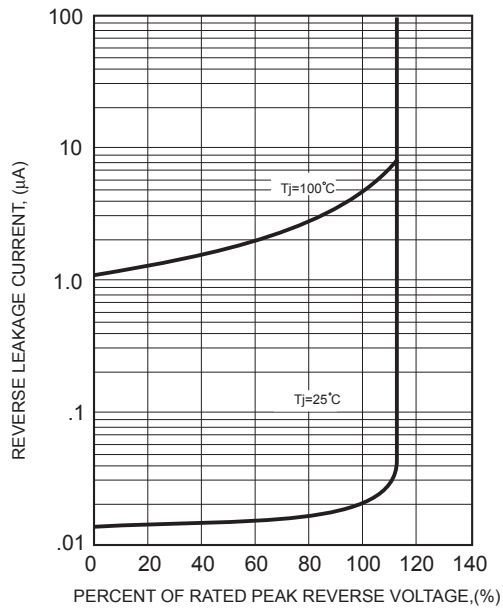


FIG.5-TYPICAL JUNCTION CAPACITANCE

